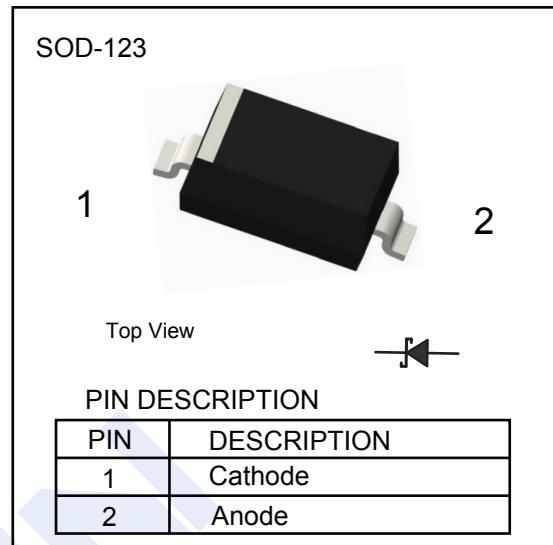


Schottky Diodes

1KK2102E ~ 1KK2104E

■ Features

- Low power loss, high efficiency
- High current capability
- Low forward voltage drop
- High Surge Capability



■ Absolute Maximum Ratings Ta = 25°C

Parameter	Symbol	1KK2102E	1KK2104E	Unit
Peak Repetitive Reverse Voltage	V _{RRM}	20	40	V
RMS Voltage	V _{RMS}	14	28	
DC Blocking Voltage	V _{DC}	20	40	
Forward Voltage @ If=1A	V _F	0.45	0.6	
Forward Voltage @ If=3.1A		0.75	0.9	
Average Forward Rectified Current @ T _L =90°C	I _{FAV}	1		A
Non-Repetitive Peak Forward Surge Current @ 8.3ms	I _{FSM}	25		
Reverse Voltage Leakage Current Ta = 25°C Ta = 100°C	I _R	1		mA
		10		
Typical Junction Capacitance	C _J	110		pF
Junction Temperature	T _J	125		°C
Storage Temperature range	T _{stg}	-55 to 125		

■ Marking

NO.	1KK2102E	1KK2104E
Marking	EB	EC

Schottky Diodes

1KK2102E ~ 1KK2104E

■ Typical Characteristics

Fig.1 Forward Current Derating Curve

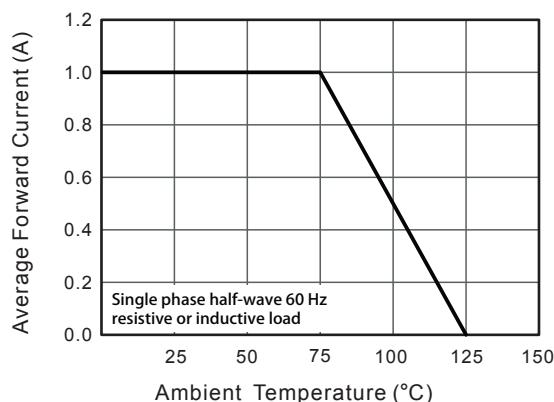


Fig.2 Typical Reverse Characteristics

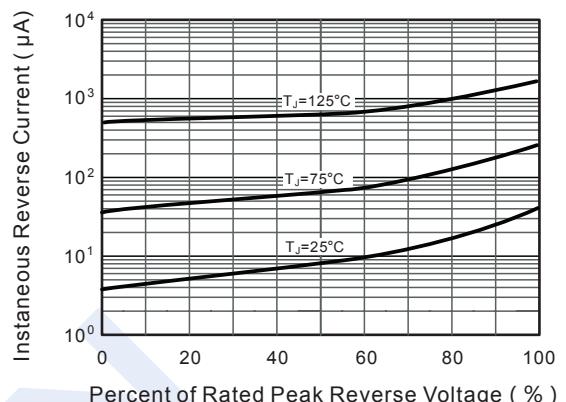


Fig.3 Typical Forward Characteristic

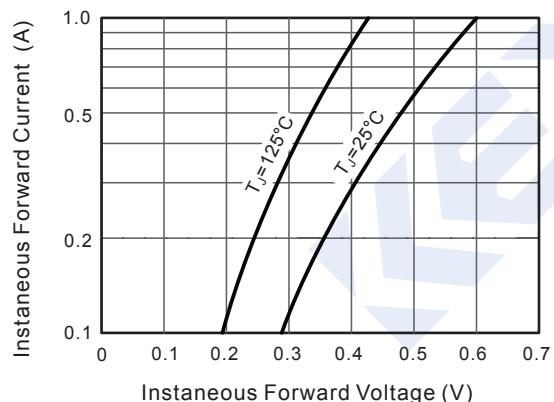


Fig.4 Typical Junction Capacitance

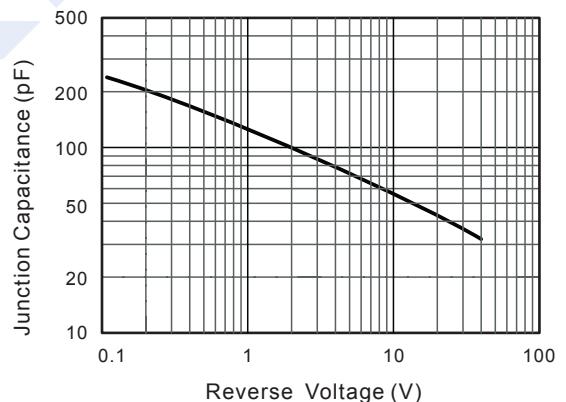


Fig.5 Maximum Non-Repetitive Peak Forward Surge Current

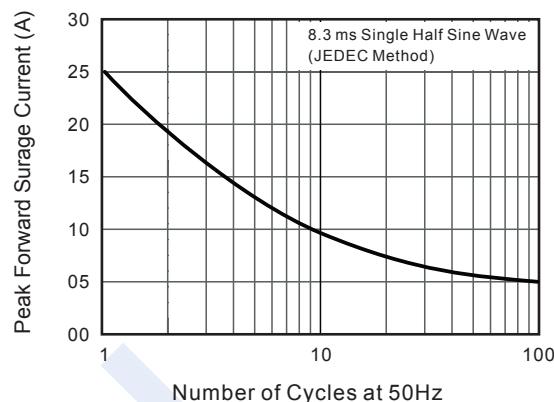
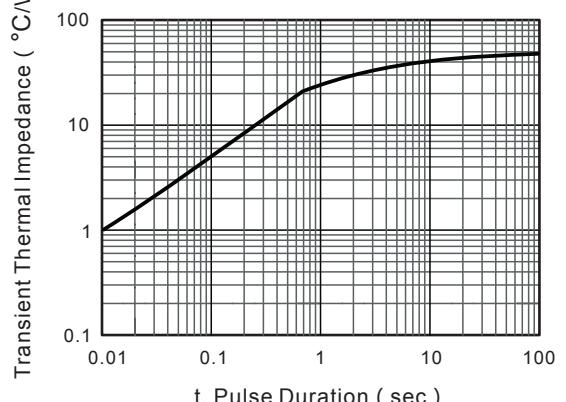


Fig.6- Typical Transient Thermal Impedance



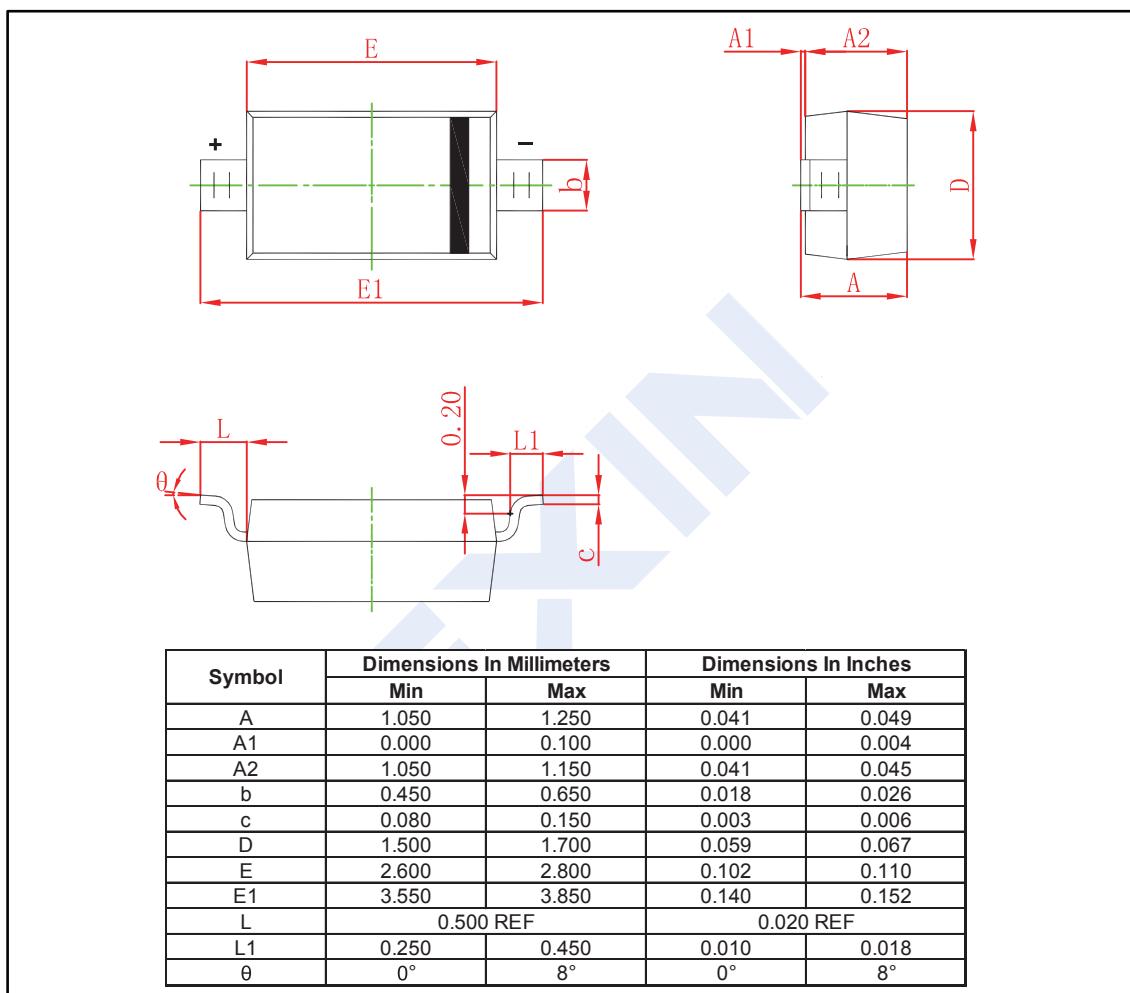
Schottky Diodes

1KK2102E ~ 1KK2104E

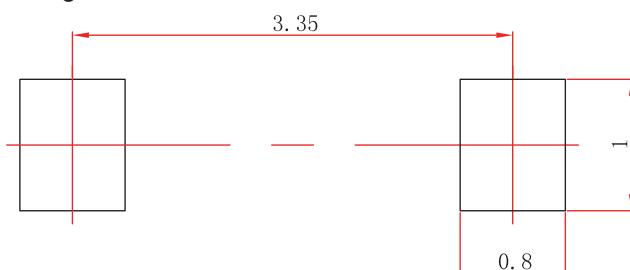
■ Package Outline Dimensions

Plastic surface mounted package; 2 leads

SOD-123



■ The Recommended Mounting Pad Size



Note:

1. Controlling dimension in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.